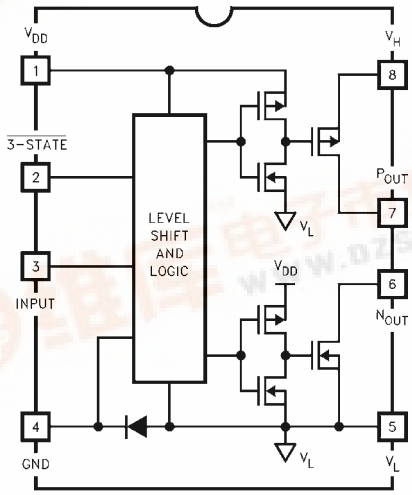
High Speed, Monolithic Pin Driver

The EL7154 3-state pin driver is particularly well suited for ATE and level shifting applications. The 4A peak drive capability, makes the EL7154 an excellent choice when driving high speed capacitive lines.

The p-channel MOSFET is completely isolated from the power supply, providing a high degree of flexibility. Pin (7) can be grounded, and the output can be taken from pin (8) when a “source follower” output is desired. Then n-channel MOSFET has an isolated drain, but shares a common bus with pre-drivers and level shifter circuits. This is necessary to ensure that the nchannel device can turn off effectively when V_L goes below GND. In some power-FET and IGBT applications, negative drive is desirable to insure effective turn-off. The EL7154 can be used in these applications by returning V_L to a moderate negative potential.

Pinout

EL7154
(8-PIN PDIP, SOIC)
TOP VIEW



Truth Table

3-STATE	INPUT	P_{OUT}	N_{OUT}
0	0	Open	Open
0	1	Open	Open
1	0	HIGH	Open
1	1	Open	LOW

Manufactured under U.S. Patent Nos. 5,334,883, #5,341,047, #5,352,578, #5,352,389, #5,351,012, #5,374,898

Features

- Comparatively low cost
- 3-State output
- 3V and 5V Input compatible
- Clocking speeds up to 10MHz
- 20ns Switching/delay time
- 4A Peak drive
- Isolated drains
- Low output impedance—2.5Ω
- Low quiescent current—5mA
- Wide operating voltage—4.5V–16V
- Isolated P-channel device
- Separate ground and V_L pins
- Pb-Free available (RoHS compliant)

Applications

- Loaded circuit board testers
- Digital testers
- Level shifting below GND
- IGBT drivers
- CCD drivers

Ordering Information

PART NUMBER	PACKAGE	TAPE & REEL	PKG. DWG. #
EL7154CN	8-Pin PDIP	-	MDP0031
EL7154CS	8-Pin SOIC	-	MDP0027
EL7154CS-T7	8-Pin SOIC	7”	MDP0027
EL7154CS-T13	8-Pin SOIC	13”	MDP0027
EL7154CSZ (See Note)	8-Pin SOIC (Pb-free)	-	MDP0027
EL7154CSZ-T7 (See Note)	8-Pin SOIC (Pb-free)	7”	MDP0027
EL7154CSZ-T13 (See Note)	8-Pin SOIC (Pb-free)	13”	MDP0027

NOTE: Intersil Pb-free products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

Nominal Operating Voltage Range

PIN	MIN	MAX
V_L	-3	0
$V_{DD}–V_L$	5	15
$V_H–V_L$	2	15
$V_{DD}–V_H$	-0.5	15
V_{DD}	5	15

Absolute Maximum Ratings (T_A = 25°C)

Supply (V_{DD} to V_L; V_H–V_L, V_H to GND),
V+ to V_H 16.5V
V_L to GND . . . . . -5V
Input Pins . . . . . -0.3V below V_L to +0.3V above V_{DD}
Peak Output Current 4A

Storage Temperature Range . . . . . .-65°C to +150°C
Ambient Operating Temperature . . . . . .-40°C to +85°C
Operating Junction Temperature . . . . . 125°C
Power Dissipation
SOIC 570mW
PDIP 1050mW

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$

DC Electrical Specifications

T_A = 25°C, V_{DD} = +12V, V_H = +12V, V_L = -3V, unless otherwise specified

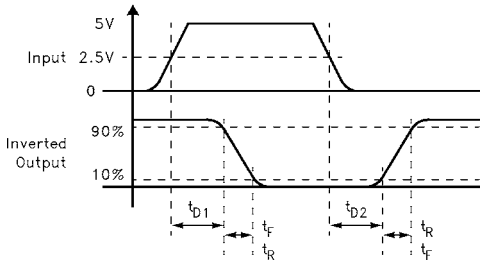
PARAMETER	DESCRIPTION	TEST CONDITIONS	MIN	TYP	MAX	UNITS
INPUT						
V_{IH}	Logic "1" Input Voltage		2.4			V
I_{IH}	Logic "1" Input Current	$V_{IH} = V_{DD}$		0.1	10	µA
V_{IL}	Logic "0" Input Voltage				0.6	V
I_{IL}	Logic "0" Input Current	V_{IL} = 0V		0.1	10	µA
V_{HVS}	Input Hysteresis			0.3		V
OUTPUT						
R_{OH}	Pull-Up Resistance	I_{OUT} = -100mA		1.5	4	Ω
R_{OL}	Pull-Down Resistance	I_{OUT} = +100mA		2	4	Ω
I_{OUT}	Output Leakage Current	V_{DD}/GND		0.2	10	µA
I_{PK}	Peak Output Current	Source Sink		4.0 4.0		A
I_{DC}	Continuous Output Current	Source/Sink	200			mA
POWER SUPPLY						
I_S	Power Supply Current	Inputs = V_{DD}		1	2.5	mA
V_S	Operating Voltage		4.5		16	V
I_G	Current to GND (Pin 4)			1	10	µA
I_H	Off Leakage at V_H	Pin 8 = 0V		1	10	µA

AC Electrical Specifications

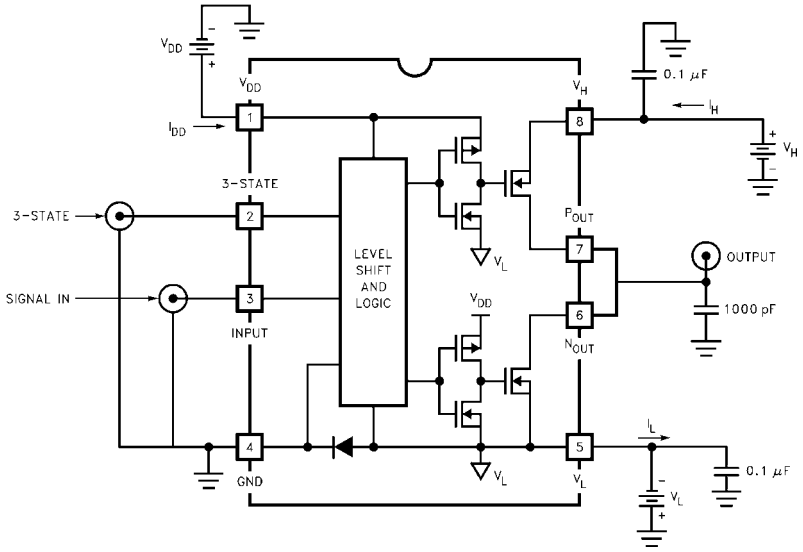
T_A = 25°C unless otherwise specified

PARAMETER	DESCRIPTION	TEST CONDITIONS	MIN	TYP	MAX	UNITS
SWITCHING CHARACTERISTICS ($V_{DD} = V_H = 12V$; $V_L = -3V$)						
t_R	Rise Time	C_L = 100pF		4	25	ns
		C_L = 2000pF		20		
t_F	Fall Time	C_L = 100pF		4	25	ns
		C_L = 2000pF		20		
t_{D-1}	Turn-Off Delay Time	C_L = 2000pF		20	25	ns
t_{D-2}	Turn-On Delay Time	C_L = 2000pF		10	25	ns
t_{D-1}	3-State Delay				25	ns
t_{D-2}	3-State Delay				25	ns

Timing Table

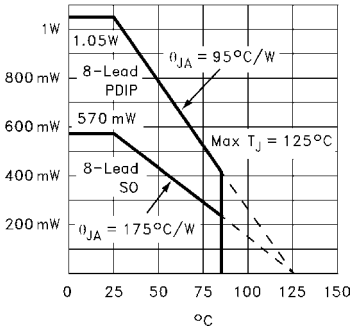


Standard Test Configuration

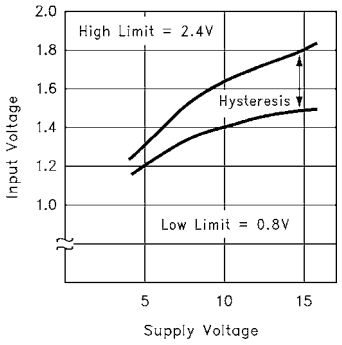


Typical Performance Curves

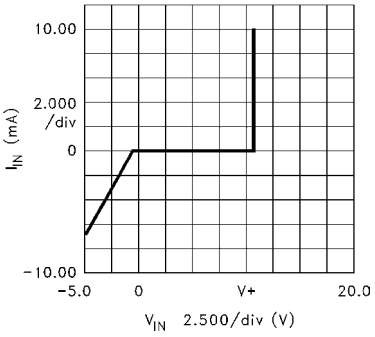
Max Power/Derating Curves



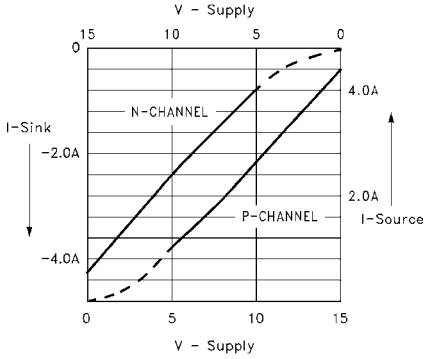
Switch Threshold vs Supply Voltage



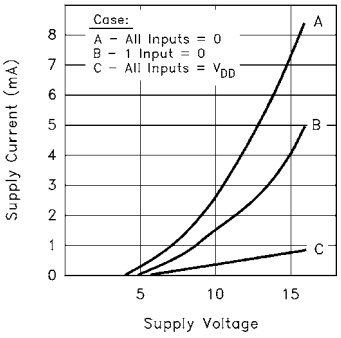
Input Current vs Voltage



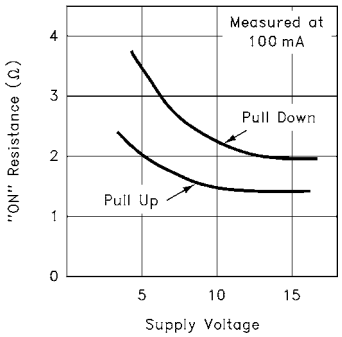
Peak Drive vs Supply Voltage



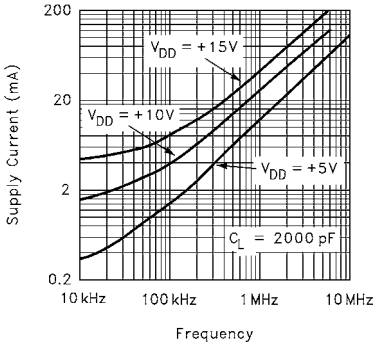
Quiescent Supply Current



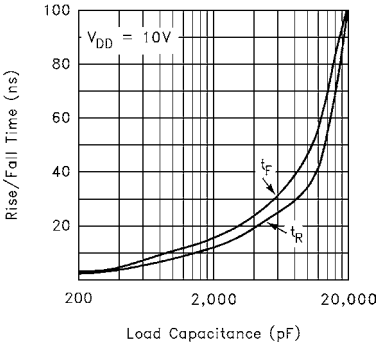
"ON" Resistance vs Supply Voltage



Average Supply Current vs Voltage and Frequency

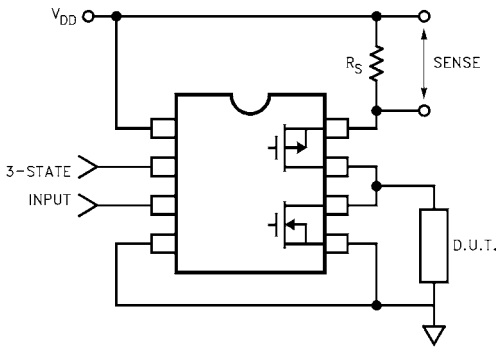


Rise/Fall Time vs Load

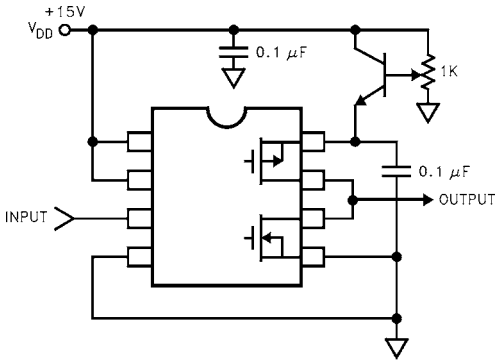


Typical Applications

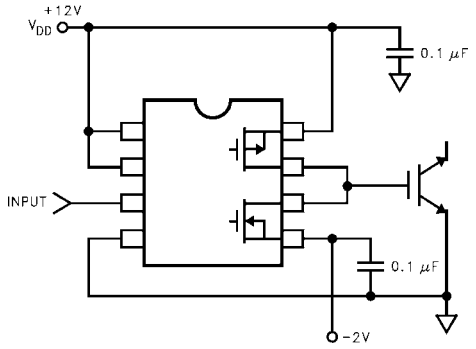
Pin Driver



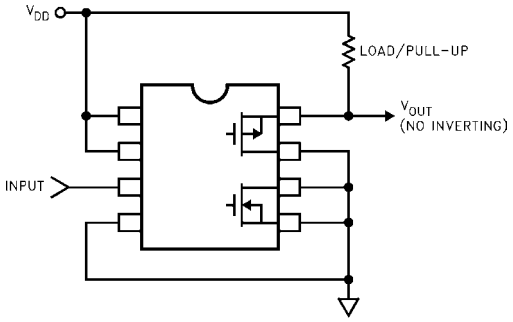
Adjustable Amplitude Pulse Generator



IGBT Driver (with Negative Swing)



PMOS Follower



Resonant Gate Driver